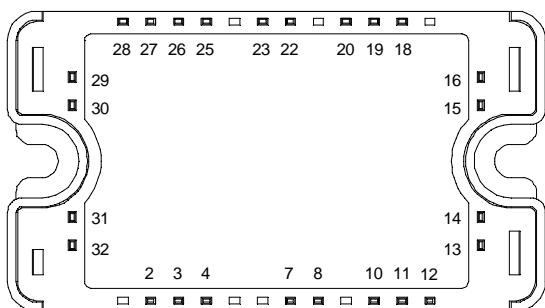
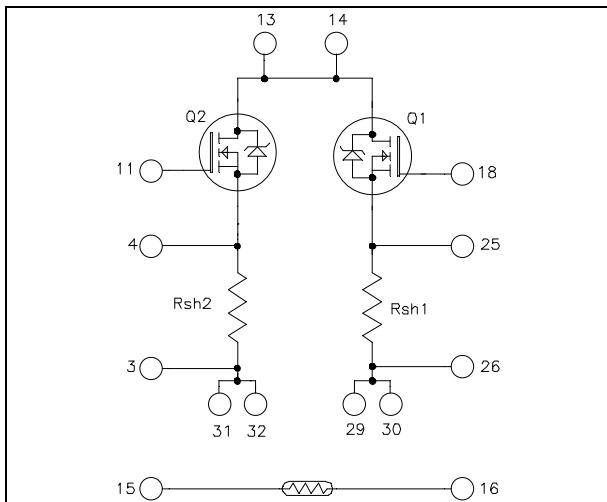


Linear MOSFET Power Module

V_{DSS} = 200V
R_{DSon} = 18mΩ typ @ T_j = 25°C
I_D = 109A* @ T_c = 25°C



Pins 13/14 ; 29/30 ; 31/32 must be shorted together

Absolute maximum ratings (per leg)

| Symbol | Parameter | Max ratings | Unit |
|-------------------|---|-----------------------|------|
| V _{DSS} | Drain - Source Breakdown Voltage | 200 | V |
| I _D | Continuous Drain Current | T _c = 25°C | 109* |
| | | T _c = 80°C | |
| I _{DM} | Pulsed Drain current | 400 | A |
| V _{GS} | Gate - Source Voltage | ±30 | |
| R _{DSon} | Drain - Source ON Resistance | 19 | mΩ |
| P _D | Maximum Power Dissipation ① | T _c = 25°C | W |
| I _{AR} | Avalanche current (repetitive and non repetitive) | 100 | A |
| E _{AR} | Repetitive Avalanche Energy | 50 | mJ |
| E _{AS} | Single Pulse Avalanche Energy | 3000 | |

* Output current per leg must be limited to 44A @ T_c=25°C and 31A @ T_c=80°C to not exceed the shunt specification.

① In saturation mode

 **CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

Electrical Characteristics (per leg)

| Symbol | Characteristic | Test Conditions | | Min | Typ | Max | Unit |
|---------------------|---------------------------------|---|---------------------------|-----|-----|-----------|------------------|
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{DS} = 200\text{V}$; $V_{GS} = 0\text{V}$ | $T_j = 25^\circ\text{C}$ | | | 25 | μA |
| | | $V_{DS} = 160\text{V}$; $V_{GS} = 0\text{V}$ | $T_j = 125^\circ\text{C}$ | | | 250 | |
| $R_{DS(on)}$ | Drain – Source on Resistance | $V_{GS} = 10\text{V}$, $I_D = 50\text{A}$ | | | 18 | 19 | $\text{m}\Omega$ |
| $V_{GS(\text{th})}$ | Gate Threshold Voltage | $V_{GS} = V_{DS}$, $I_D = 2.5\text{mA}$ | | 2 | | 4 | V |
| I_{GSS} | Gate – Source Leakage Current | $V_{GS} = \pm 30\text{ V}$ | | | | ± 100 | nA |

Dynamic Characteristics (per leg)

| Symbol | Characteristic | Test Conditions | | Min | Typ | Max | Unit |
|-----------|------------------------------|--|--|-----|------|-----|-------------|
| C_{iss} | Input Capacitance | $V_{GS} = 0\text{V}$ $V_{DS} = 25\text{V}$ $f = 1\text{MHz}$ | | | 9880 | | pF |
| C_{oss} | Output Capacitance | | | | 2320 | | |
| C_{rss} | Reverse Transfer Capacitance | | | | 700 | | |

Shunt Electrical Characteristics (per leg)

| Symbol | Characteristic | | | Min | Typ | Max | Unit |
|----------|------------------|--|------------------------|-----|-----|-----|------------------|
| R_{sh} | Resistance value | | | | 10 | | $\text{m}\Omega$ |
| T_{sh} | Tolerance | | | | 2 | | % |
| P_{sh} | Load capacity | | $T_C=25^\circ\text{C}$ | | | 20 | W |
| | | | $T_C=80^\circ\text{C}$ | | | 10 | |
| I_{sh} | Current capacity | | $T_C=25^\circ\text{C}$ | | | 44 | A |
| | | | $T_C=80^\circ\text{C}$ | | | 31 | |

Temperature sensor PTC

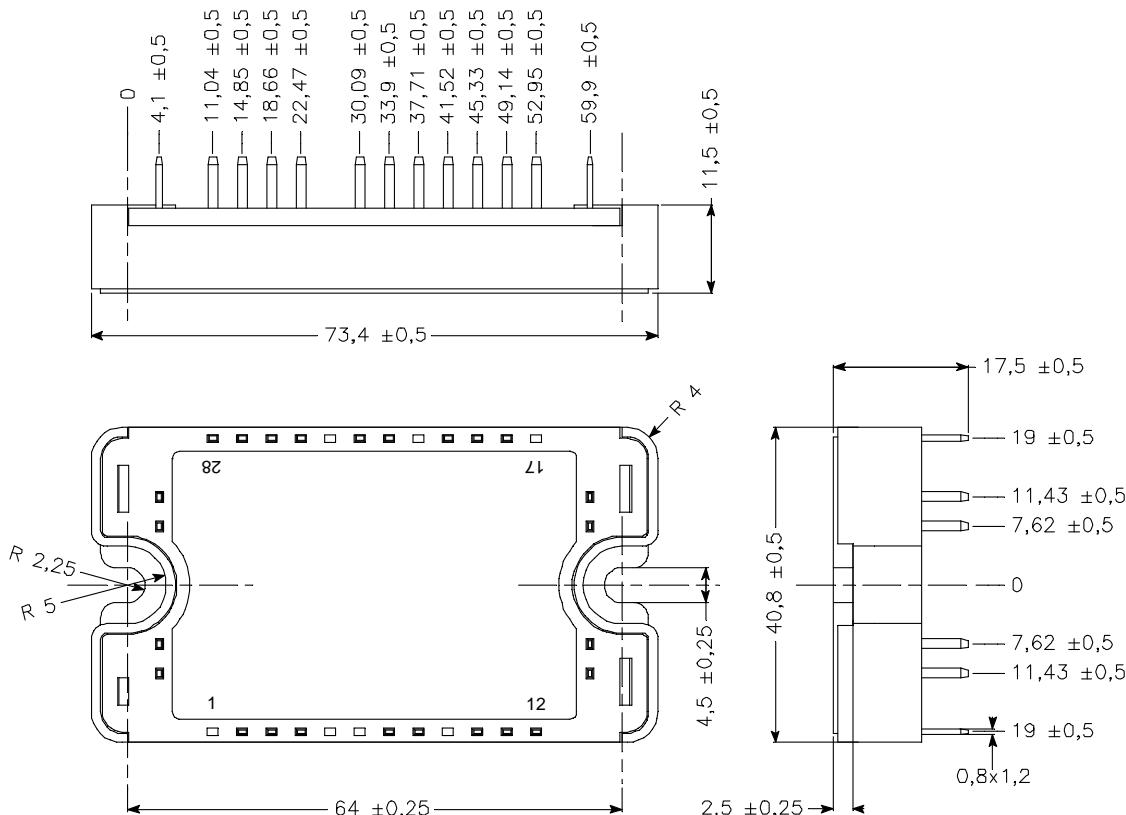
| Symbol | Characteristic | | | Min | Typ | Max | Unit |
|------------------|---------------------------------|--|--|-------|-------|-------|----------------|
| R_{25} | Resistance @ 25°C | | | 1980 | | 2020 | Ω |
| R_{100}/R_{25} | Resistance ratio | $\text{Tamb}=100^\circ\text{C} & 25^\circ\text{C}$ | | 1.676 | 1.696 | 1.716 | |
| R_{-55}/R_{25} | Resistance ratio | $\text{Tamb}=-55^\circ\text{C} & 25^\circ\text{C}$ | | 0.48 | 0.49 | 0.50 | |
| B | Temperature coefficient | | | | 7900 | | ppm/K |

Thermal and package characteristics

| Symbol | Characteristic | | | Min | Typ | Max | Unit |
|------------|--|------------------|------|-----|------|-----|--------------------|
| R_{thJC} | Junction to Case Thermal Resistance | MOSFET (per leg) | | | 0.26 | | $^\circ\text{C/W}$ |
| V_{ISOL} | RMS Isolation Voltage, any terminal to case t = 1 min, $I_{isol}<1\text{mA}$, 50/60Hz | | 4000 | | | | V |
| T_j | Operating junction temperature range | | -40 | | 150 | | $^\circ\text{C}$ |
| T_{STG} | Storage Temperature Range | | -40 | | 125 | | |
| T_c | Operating Case Temperature | | -40 | | 100 | | |
| Torque | Mounting torque | To heatsink | M4 | 2.5 | | 4.7 | N.m |
| Wt | Package Weight | | | | 110 | | g |

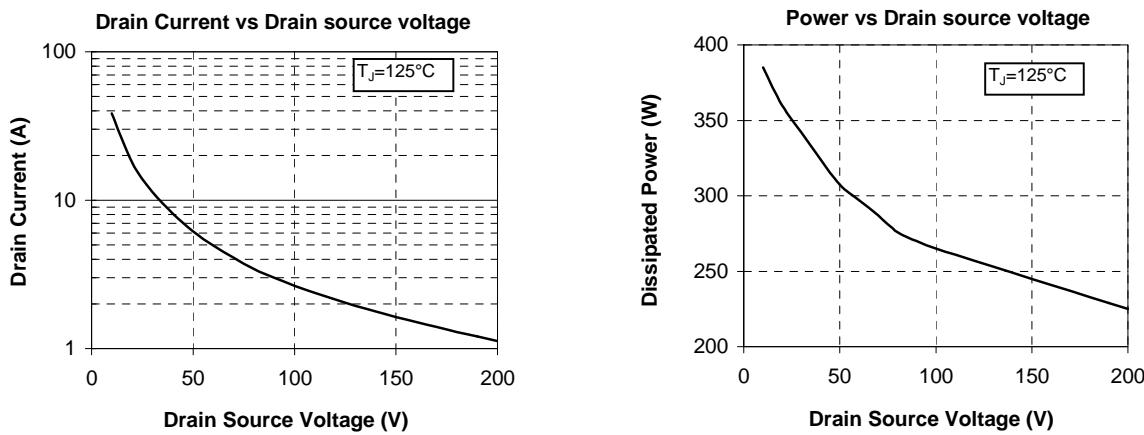


SP3 Package outline (dimensions in mm)



See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

Typical Performance Curve (linear mode) (per leg)



Microsemi reserves the right to change, without notice, the specifications and information contained herein

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